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This handbook presents electronic structure data and tabulations of Slater-Koster parameters for the whole periodic table. This second edition presents data sets for all elements up to $Z = 112$, Copernicium, whereas the first edition contained only 53 elements. In this new edition, results are given for the equation of state of the elements together with the parameters of a Birch fit, so that the reader can regenerate the results and derive additional information, such as Pressure-Volume relations and variation of Bulk Modulus with Pressure. For each element, in addition to the equation of state, the energy bands, densities of states and a set of tight-binding parameters is provided. For a majority of elements, the tight-binding parameters are presented for both a two- and three-center approximation. For the hcp structure, new three-center tight-binding results are given. Other new material in this edition include: energy bands and densities of states of all rare-earth metals, a discussion of the McMillan-Gaspari-Gyorffy theories and a tabulation of the electron-ion interaction matrix elements. The evaluation of the Stoner criterion for ferromagnetism is examined and results are tabulated. This edition also contains two new appendices discussing the effects of spin-orbit interaction and a modified version of Harrison's tight-binding theory for metals which puts the theory on a quantitative basis.

This book reviews some of the classic aspects in the theory of phase transitions and critical phenomena, which has a long history. Recently, these aspects are attracting much attention

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due to essential new contributions. The topics presented in this book include: mathematical theory of the Ising model; equilibrium and non-equilibrium criticality of one-dimensional quantum spin chains; influence of structural disorder on the critical behaviour of the Potts model; criticality, fractality and multifractality of linked polymers; field-theoretical approaches in the superconducting phase transitions. The book is based on the review lectures that were given in Lviv (Ukraine) in March 2002 at the "Ising lectures" — a traditional annual workshop on phase transitions and critical phenomena which aims to bring together scientists working in the field of phase transitions with university students and those who are interested in the subject. Contents: Mathematical Theory of the Ising Model and Its Generalizations: An Introduction (Y Kozitsky) Relaxation in Quantum Spin Chains: Free Fermionic Models (D Karevski) Quantum Phase Transitions in Alternating Transverse Ising Chains (O Derzhko) Phase Transitions in Two-Dimensional Random Potts Models (B Berche & C Chatelain) Scaling of Miktoarm Star Polymers (C von Ferber) Field Theoretic Approaches to the Superconducting Phase Transition (F S Nogueira & H Kleinert) Readership: Researchers, academics and graduate students in condensed matter physics. Keywords: Phase Transitions; Disorder; Critical Phenomena; Renormalization Group; Ising Model; Potts Model

A practical guide to semiconductor manufacturing from process control to yield modeling and experimental design Fundamentals of Semiconductor Manufacturing and Process Control covers all issues involved in manufacturing microelectronic devices and circuits, including fabrication sequences, process control, experimental design, process modeling, yield modeling, and CIM/CAM systems. Readers are introduced to both the theory and practice of all basic manufacturing concepts. Following an overview of

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manufacturing and technology, the text explores process monitoring methods, including those that focus on product wafers and those that focus on the equipment used to produce wafers. Next, the text sets forth some fundamentals of statistics and yield modeling, which set the foundation for a detailed discussion of how statistical process control is used to analyze quality and improve yields. The discussion of statistical experimental design offers readers a powerful approach for systematically varying controllable process conditions and determining their impact on output parameters that measure quality. The authors introduce process modeling concepts, including several advanced process control topics such as run-by-run, supervisory control, and process and equipment diagnosis. Critical coverage includes the following:

- * Combines process control and semiconductor manufacturing
- * Unique treatment of system and software technology and management of overall manufacturing systems
- * Chapters include case studies, sample problems, and suggested exercises
- * Instructor support includes electronic copies of the figures and an instructor's manual

Graduate-level students and industrial practitioners will benefit from the detailed examination of how electronic materials and supplies are converted into finished integrated circuits and electronic products in a high-volume manufacturing environment. An Instructor's Manual presenting detailed solutions to all the problems in the book is available from the Wiley editorial department. An Instructor Support FTP site is also available.

The Handbook Series on Semiconductor Parameters will consist of 5 volumes and will include data on the most popular semiconductor materials. These volumes aim to be a basic reference for scientists, engineers, students and technicians working in semiconductor materials and devices. The books have been kept compact but comprehensive and

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contain the values of frequently needed parameters selected and commented by leading experts on these materials. The first volume will include data on Si, Ge, diamond, GaAs, GaP, GaSb, InAs, InP, and InSb

Knowledge of the refractive indices and absorption coefficients of semiconductors is especially important in the design and analysis of optical and photonic devices. This book presents data on the optical constants of various elemental and compound semiconductors. A complete set of the optical constants of the semiconductors are presented in tabular and graphical forms over the entire photon-energy range. They are: the complex dielectric constant $\epsilon(E)=\epsilon_1(E)+i\epsilon_2(E)$, the complex refractive index $n^*(E)=n(E)+ik(E)$, the absorption coefficient $a(E)$, and the normal-incidence reflectivity $R(E)$. The book will aid many who are interested to know the optical constants of the elemental and compound semiconductors in the course of their work.

This book focusses on III-V high electron mobility transistors (HEMTs) including basic physics, material used, fabrications details, modeling, simulation, and other important aspects. It initiates by describing principle of operation, material systems and material technologies followed by description of the structure, I-V characteristics, modeling of DC and RF parameters of AlGaIn/GaN HEMTs. The book also provides information about source/drain engineering, gate engineering and channel engineering techniques used to improve the DC-RF and breakdown performance of HEMTs. Finally, the book also highlights the importance of metal oxide semiconductor high electron mobility transistors (MOS-HEMT). Key Features Combines III-As/P/N HEMTs with reliability and current status in single volume Includes AC/DC modelling and (sub)millimeter wave devices with reliability analysis Covers all theoretical and experimental aspects of HEMTs Discusses

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AlGaIn/GaN transistors Presents DC, RF and breakdown characteristics of HEMTs on various material systems using graphs and plots

Optoelectronics has become an important part of our lives. Wherever light is used to transmit information, tiny semiconductor devices are needed to transfer electrical current into optical signals and vice versa. Examples include light emitting diodes in radios and other appliances, photodetectors in elevator doors and digital cameras, and laser diodes that transmit phone calls through glass fibers. Such optoelectronic devices take advantage of sophisticated interactions between electrons and light. Nanometer scale semiconductor structures are often at the heart of modern optoelectronic devices. Their shrinking size and increasing complexity make computer simulation an important tool to design better devices that meet ever rising performance requirements. The current need to apply advanced design software in optoelectronics follows the trend observed in the 1980's with simulation software for silicon devices. Today, software for technology computer-aided design (TCAD) and electronic design automation (EDA) represents a fundamental part of the silicon industry. In optoelectronics, advanced commercial device software has emerged recently and it is expected to play an increasingly important role in the near future. This book will enable students, device engineers, and researchers to more effectively use advanced design software in optoelectronics. Provides fundamental knowledge in semiconductor physics and in electromagnetics, while helping to understand and use advanced device simulation software Demonstrates the combination of measurements and simulations in order to obtain realistic results and provides data on all required material parameters Gives deep insight into the physics of state-of-the-art devices and helps to design and analyze of modern optoelectronic devices

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Enormous leaps forward in the efficiency and the economy of solar cells are being made at a furious pace. New materials and manufacturing processes have opened up new realms of possibility for the application of solar cells. Crystalline silicon cells are increasingly making way for thin film cells, which are spawning experimentation with third-generation high-efficiency multijunction cells, carbon-nanotube based cells, UV light for voltage enhancement, and the use of the infrared spectrum for night-time operation, to name only a few recent advances. This thoroughly updated new edition of Markvart and Castaner's Solar Cells, extracted from their industry standard Practical Handbook of Photovoltaics, is the definitive reference covering the science and operation, materials and manufacture of solar cells. It is essential reading for engineers, installers, designers, and policy-makers who need to understand the science behind the solar cells of today, and tomorrow, in order to take solar energy to the next level. A thorough update to the definitive reference to solar cells, created by a cast of international experts from industry and academia to ensure the highest quality information from multiple perspectives Covers the whole spectrum of solar cell information, from basic scientific background, to the latest advances in materials, to manufacturing issues, to testing and calibration. Case studies, practical examples and reports on the latest advances take the new edition of this amazing resource beyond a simple amalgamation of a vast amount of knowledge, into the realm of real world applications

Reliability and Failure of Electronic Materials and

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Devices is a well-established and well-regarded reference work offering unique, single-source coverage of most major topics related to the performance and failure of materials used in electronic devices and electronics packaging. With a focus on statistically predicting failure and product yields, this book can help the design engineer, manufacturing engineer, and quality control engineer all better understand the common mechanisms that lead to electronics materials failures, including dielectric breakdown, hot-electron effects, and radiation damage. This new edition adds cutting-edge knowledge gained both in research labs and on the manufacturing floor, with new sections on plastics and other new packaging materials, new testing procedures, and new coverage of MEMS devices. Covers all major types of electronics materials degradation and their causes, including dielectric breakdown, hot-electron effects, electrostatic discharge, corrosion, and failure of contacts and solder joints New updated sections on "failure physics," on mass transport-induced failure in copper and low-k dielectrics, and on reliability of lead-free/reduced-lead solder connections New chapter on testing procedures, sample handling and sample selection, and experimental design Coverage of new packaging materials, including plastics and composites Practical Handbook of Photovoltaics, Third Edition, is a 'benchmark' publication for those involved in the design, manufacture and use of these devices. This fully revised handbook includes brand new sections on smart grids, net metering and the modeling of photovoltaic systems, as well as fully revised content on developments in

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photovoltaic applications, the economics of PV manufacturing and updated chapters on solar cell function, raw materials, photovoltaic standards, calibration and testing, all with new examples and case studies. The editor has assembled internationally-respected contributors from industry and academia around the world to make this a truly global reference. It is essential reading for electrical engineers, designers of systems, installers, architects, policymakers and physicists working with photovoltaics. Presents a cast of international experts from industry and academia to ensure the highest quality information from multiple stakeholder perspectives Covers all things photovoltaics, from the principles of solar cell function and their raw materials, to the installation and design of full photovoltaic systems Includes case studies, practical examples, and reports on the latest advances and worldwide applications

The Handbook Series on Semiconductor Parameters will consist of 5 volumes and will include data on the most popular semiconductor materials. These volumes aim to be a basic reference for scientists, engineers, students and technicians working in semiconductor materials and devices. The books have been kept compact but comprehensive and contain the values of frequently needed parameters selected and commented by leading experts on these materials. The first volume will include data on Si, Ge, diamond, GaAs, GaP, GaSb, InAs, InP, and InSb.

The first part provides a general introduction to the electronic structure of quasi-two-dimensional systems

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with a particular focus on group-theoretical methods. The main part of the monograph is devoted to spin-orbit coupling phenomena at zero and nonzero magnetic fields. Throughout the book, the main focus is on a thorough discussion of the physical ideas and a detailed interpretation of the results. Accurate numerical calculations are complemented by simple and transparent analytical models that capture the important physics.

Proudly serving the scientific community for over a century, this 96th edition of the CRC Handbook of Chemistry and Physics is an update of a classic reference, mirroring the growth and direction of science. This venerable work continues to be the most accessed and respected scientific reference in the world. An authoritative resource consisting of tables of data and current international recommendations on nomenclature, symbols, and units, its usefulness spans not only the physical sciences but also related areas of biology, geology, and environmental science. The 96th edition of the Handbook includes 18 new or updated tables along with other updates and expansions. A new series highlighting the achievements of some of the major historical figures in chemistry and physics was initiated with the 94th edition. This series is continued with this edition, which is focused on Lord Kelvin, Michael Faraday, John Dalton, and Robert Boyle. This series, which provides biographical information, a list of major achievements, and notable quotations attributed to each of the renowned chemists and physicists, will be continued in succeeding editions. Each edition will

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feature two chemists and two physicists. The 96th edition now includes a complimentary eBook with purchase of the print version. This reference puts physical property data and mathematical formulas used in labs and classrooms every day within easy reach. New Tables:

Section 1: Basic Constants, Units, and Conversion Factors
Descriptive Terms for Solubility
Section 8: Analytical Chemistry Stationary Phases for Porous Layer Open Tubular Columns
Coolants for Cryotrapping
Instability of HPLC Solvents
Chlorine-Bromine Combination Isotope Intensities
Section 16: Health and Safety Information
Materials Compatible with and Resistant to 72 Percent Perchloric Acid
Relative Dose Ranges from Ionizing Radiation
Updated and Expanded Tables
Section 6: Fluid Properties
Sublimation Pressure of Solids
Vapor Pressure of Fluids at Temperatures Below 300 K
Section 7: Biochemistry
Structure and Functions of Some Common Drugs
Section 9: Molecular Structure and Spectroscopy
Bond Dissociation Energies
Section 11: Nuclear and Particle Physics
Summary Tables of Particle Properties
Table of the Isotopes
Section 14: Geophysics, Astronomy, and Acoustics
Major World Earthquakes
Atmospheric Concentration of Carbon Dioxide, 1958-2014
Global Temperature Trend, 1880-2014
Section 15: Practical Laboratory Data
Dependence of Boiling Point on Pressure
Section 16: Health and Safety Information
Threshold Limits for Airborne Contaminants

Fundamentals of III-V Semiconductor MOSFETs presents the fundamentals and current status of research of compound semiconductor metal-oxide-

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semiconductor field-effect transistors (MOSFETs) that are envisioned as a future replacement of silicon in digital circuits. The material covered begins with a review of specific properties of III-V semiconductors and available technologies making them attractive to MOSFET technology, such as band-engineered heterostructures, effect of strain, nanoscale control during epitaxial growth. Due to the lack of thermodynamically stable native oxides on III-V's (such as SiO₂ on Si), high-k oxides are the natural choice of dielectrics for III-V MOSFETs. The key challenge of the III-V MOSFET technology is a high-quality, thermodynamically stable gate dielectric that passivates the interface states, similar to SiO₂ on Si. Several chapters give a detailed description of materials science and electronic behavior of various dielectrics and related interfaces, as well as physics of fabricated devices and MOSFET fabrication technologies. Topics also include recent progress and understanding of various materials systems; specific issues for electrical measurement of gate stacks and FETs with low and wide bandgap channels and high interface trap density; possible paths of integration of different semiconductor materials on Si platform.

This practical resource offers expert guidance on the most critical aspects of microwave power amplifier design. This comprehensive book provides descriptions of all the major active devices, discusses large signal characterization, explains all the key circuit design procedures. Moreover you gain keen insight on the link between design parameters and technological implementation, helping you achieve optimal solutions with the most efficient utilization of available

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technologies. The book covers a broad range of essential topics, from requirements for high-power amplifiers, device models, phase noise and power combiners. to high-efficiency amplifiers, linear amplifier design, bias circuits, and thermal design.

After many years of research and development, silicon carbide has emerged as one of the most important wide band gap semiconductors. The first commercial SiC devices OCo power switching Schottky diodes and high temperature MESFETs OCo are now on the market. This two-volume book gives a comprehensive, up-to-date review of silicon carbide materials properties and devices. With contributions by recognized leaders in SiC technology and materials and device research, SiC Materials and Devices is essential reading for technologists, scientists and engineers who are working on silicon carbide or other wide band gap materials and devices. The volumes can also be used as supplementary textbooks for graduate courses on silicon carbide and wide band gap semiconductor technology.

Contents: SiC Material Properties (G Pensl et al.); SiC Homoepitaxy and Heteroepitaxy (A S Bakin); Ohmic Contacts to SiC (F Roccaforte et al.); Silicon Carbide Schottky Barrier Diode (J H Zhao et al.); High Power SiC PiN Rectifiers (R Singh); Silicon Carbide Diodes for Microwave Applications (K Vassilevski); SiC Thyristors (M E Levinshtein et al.); Silicon Carbide Static Induction Transistors (G C DeSalvo).

Readership: Technologists, scientists, engineers and graduate students working on silicon carbide or other wide band gap materials and devices."

Resistivity -- Carrier and doping density -- Contact resistance and Schottky barriers -- Series resistance, channel length and width, and threshold voltage -- Defects -- Oxide and interface trapped charges, oxide thickness -- Carrier lifetimes -- Mobility -- Charge-based and probe characterization -- Optical

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characterization -- Chemical and physical characterization --
Reliability and failure analysis.

Excellent bridge between general solid-state physics textbook and research articles packed with providing detailed explanations of the electronic, vibrational, transport, and optical properties of semiconductors "The most striking feature of the book is its modern outlook ... provides a wonderful foundation. The most wonderful feature is its efficient style of exposition ... an excellent book." Physics Today "Presents the theoretical derivations carefully and in detail and gives thorough discussions of the experimental results it presents. This makes it an excellent textbook both for learners and for more experienced researchers wishing to check facts. I have enjoyed reading it and strongly recommend it as a text for anyone working with semiconductors ... I know of no better text ... I am sure most semiconductor physicists will find this book useful and I recommend it to them." Contemporary Physics Offers much new material: an extensive appendix about the important and by now well-established, deep center known as the DX center, additional problems and the solutions to over fifty of the problems at the end of the various chapters.

Handbook Series on Semiconductor Parameters Ternary and quaternary III-V compounds World Scientific

The self-assembled nanostructured materials described in this book offer a number of advantages over conventional material technologies in a wide range of sectors. World leaders in the field of self-organisation of nanostructures review the current status of research and development in the field, and give an account of the formation, properties, and self-organisation of semiconductor nanostructures. Chapters on structural, electronic and optical properties, and devices based on self-organised nanostructures are also included. Future research work on self-assembled nanostructures will

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connect diverse areas of material science, physics, chemistry, electronics and optoelectronics. This book will provide an excellent starting point for workers entering the field and a useful reference to the nanostructured materials research community. It will be useful to any scientist who is involved in nanotechnology and those wishing to gain a view of what is possible with modern fabrication technology. Mohamed Henini is a Professor of Applied Physics at the University of Nottingham. He has authored and co-authored over 750 papers in international journals and conference proceedings and is the founder of two international conferences. He is the Editor-in-Chief of Microelectronics Journal and has edited three previous Elsevier books. Contributors are world leaders in the field Brings together all the factors which are essential in self-organisation of quantum nanostructures Reviews the current status of research and development in self-organised nanostructured materials Provides a ready source of information on a wide range of topics Useful to any scientist who is involved in nanotechnology Excellent starting point for workers entering the field Serves as an excellent reference manual

In his 1959 address, "There is Plenty of Room at the Bottom," Richard P. Feynman speculated about manipulating materials atom by atom and challenged the technical community "to find ways of manipulating and controlling things on a small scale." This visionary challenge has now become a reality, with recent advances enabling atomistic-level tailoring and control of materials. Exemplifying Feynman's vision, Handbook of Nanoscience, Engineering, and Technology, Third Edition continues to explore innovative nanoscience, engineering, and technology areas. Along with updating all chapters, this third edition extends the coverage of emerging nano areas even further. Two entirely new sections on energy and biology cover nanomaterials for energy storage devices,

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photovoltaics, DNA devices and assembly, digital microfluidic lab-on-a-chip, and much more. This edition also includes new chapters on nanomagnet logic, quantum transport at the nanoscale, terahertz emission from Bloch oscillator systems, molecular logic, electronic optics in graphene, and electromagnetic metamaterials. With contributions from top scientists and researchers from around the globe, this color handbook presents a unified, up-to-date account of the most promising technologies and developments in the nano field. It sets the stage for the next revolution of nanoscale manufacturing—where scalable technologies are used to manufacture large numbers of devices with complex functionalities.

Electrochemistry plays a key role in a broad range of research and applied areas including the exploration of new inorganic and organic compounds, biochemical and biological systems, corrosion, energy applications involving fuel cells and solar cells, and nanoscale investigations. The Handbook of Electrochemistry serves as a source of electrochemical information, providing details of experimental considerations, representative calculations, and illustrations of the possibilities available in electrochemical experimentation. The book is divided into five parts: Fundamentals, Laboratory Practical, Techniques, Applications, and Data. The first section covers the fundamentals of electrochemistry which are essential for everyone working in the field, presenting an overview of electrochemical conventions, terminology, fundamental equations, and electrochemical cells, experiments, literature, textbooks, and specialized books. Part 2 focuses on the different laboratory aspects of electrochemistry which is followed by a review of the various electrochemical techniques ranging from classical experiments to scanning electrochemical microscopy, electrogenerated chemiluminescence and

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spectroelectrochemistry. Applications of electrochemistry include electrode kinetic determinations, unique aspects of metal deposition, and electrochemistry in small places and at novel interfaces and these are detailed in Part 4. The remaining three chapters provide useful electrochemical data and information involving electrode potentials, diffusion coefficients, and methods used in measuring liquid junction potentials. * serves as a source of electrochemical information * includes useful electrochemical data and information involving electrode potentials, diffusion coefficients, and methods used in measuring liquid junction potentials * reviews electrochemical techniques (incl. scanning electrochemical microscopy, electrogenerated chemiluminescence and spectroelectrochemistry)

Rapid developments in technology have led to enhanced electronic systems and applications. When utilized correctly, these can have significant impacts on communication and computer systems. Transport of Information-Carriers in Semiconductors and Nanodevices is an innovative source of academic material on transport modelling in semiconductor material and nanoscale devices. Including a range of perspectives on relevant topics such as charge carriers, semiclassical transport theory, and organic semiconductors, this is an ideal publication for engineers, researchers, academics, professionals, and practitioners interested in emerging developments on transport equations that govern information carriers.

Microring/nanoring resonator is an interesting device that has been widely studied and investigated by researchers from a variety of specializations. This book begins with the basic background of linear and nonlinear ring resonators. A novel design of nano device known as a PANDA ring resonator is proposed. The use of the device in the form of a PANDA in applications such as nanoelectronics, measurement,

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communication, sensors, optical and quantum computing, drug delivery, hybrid transistor and a new concept of electron-hole pair is discussed in detail.

Top-Down VLSI Design: From Architectures to Gate-Level Circuits and FPGAs represents a unique approach to learning digital design. Developed from more than 20 years teaching circuit design, Doctor Kaeslin's approach follows the natural VLSI design flow and makes circuit design accessible for professionals with a background in systems engineering or digital signal processing. It begins with hardware architecture and promotes a system-level view, first considering the type of intended application and letting that guide your design choices. Doctor Kaeslin presents modern considerations for handling circuit complexity, throughput, and energy efficiency while preserving functionality. The book focuses on application-specific integrated circuits (ASICs), which along with FPGAs are increasingly used to develop products with applications in telecommunications, IT security, biomedical, automotive, and computer vision industries. Topics include field-programmable logic, algorithms, verification, modeling hardware, synchronous clocking, and more. Demonstrates a top-down approach to digital VLSI design. Provides a systematic overview of architecture optimization techniques. Features a chapter on field-programmable logic devices, their technologies and architectures. Includes checklists, hints, and warnings for various design situations. Emphasizes design flows that do not overlook important action items and which include alternative options when planning the development of microelectronic circuits.

As part of the growing sustainable and renewable energy movement, the design, manufacture and use of photovoltaic devices is increasing in pace and frequency. The Handbook of Photovoltaics will be a 'benchmark' publication for those involved in the design, manufacture and use of these devices.

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The Handbook covers the principles of solar cell function, the raw materials, photovoltaic systems, standards, calibration, testing, economics and case studies. The editors have assembled a cast of internationally-respected contributors from industry and academia. The report is essential reading for: Physicists, electronic engineers, designers of systems, installers, architects, policy-makers relating to photovoltaics. The Handbook Series on Semiconductor Parameters will consist of 5 volumes and will include data on the most popular semiconductor materials. These volumes aim to be a basic reference for scientists, engineers, students and technicians working in semiconductor materials and devices. The books have been kept compact but comprehensive and contain the values of frequently needed parameters selected and commented by leading experts on these materials. The first volume will include data on Si, Ge, diamond, GaAs, GaP, GaSb, InAs, InP, and InSb.

Containing the most reliable parameter values for each of these semiconductor materials, along with applicable references, these data are organized in a structured, logical way for each semiconductor material. * Reviews traditional semiconductor materials as well as new, advanced semiconductors. * Essential authoritative handbook on the properties of semiconductor materials.

Concentrator Photovoltaics (CPV) is one of the most promising technologies to produce solar electricity at competitive prices. High performing CPV systems with efficiencies well over 30% and multi-megawatt CPV plants are now a reality. As a result of these achievements, the global CPV market is expected to grow dramatically over the next few years reaching cumulative installed capacity of 12.5 GW by 2020. In

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this context, both new and consolidated players are moving fast to gain a strategic advantage in this emerging market. Written with clear, brief and self-contained technical explanations, Handbook of Concentrator Photovoltaic Technology provides a complete overview of CPV covering: the fundamentals of solar radiation, solar cells, concentrator optics, modules and trackers; all aspects of characterization and reliability; case studies based on the description of actual systems and plants in the field; environmental impact, market potential and cost analysis. CPV technology is at a key point of expansion. This timely handbook aims to provide a comprehensive assessment of all CPV scientific, technological and engineering background with a view to equipping engineers and industry professionals with all of the vital information they need to help them sustain the impetus of this encouraging technology. Key features: Uniquely combines an explanation of the fundamentals of CPV systems and components with an overview of the market place and their real-life applications. Each chapter is written by well-known industry specialists with extensive expertise in each particular field of CPV technology. Reviews the basic concepts of multi-junction solar cells and new concepts for CPV cells, highlighting the key differences between them. Demonstrates the state of the art of several CPV centres and companies. Facilitates future cost

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calculation models for CPV. Features extensive case studies in each chapter, including coverage of CPV modules and systems.

Proudly serving the scientific community for over a century, this 95th edition of the CRC Handbook of Chemistry and Physics is an update of a classic reference, mirroring the growth and direction of science. This venerable work continues to be the most accessed and respected scientific reference in the world. An authoritative resource consisting of tables of data and current international recommendations on nomenclature, symbols, and units, its usefulness spans not only the physical sciences but also related areas of biology, geology, and environmental science. The 95th Edition of the Handbook includes 22 new tables and major updates and expansions. A new series highlighting the achievements of some of the major historical figures in chemistry and physics was initiated with the 94th edition. This series is continued with this edition, which is focused on Galileo Galilei, James Clerk Maxwell, Marie Skłodowska Curie, and Linus Carl Pauling. This series, which provides biographical information, a list of major achievements, and notable quotations attributed to each of the renowned chemists and physicists, will be continued in succeeding editions. Each edition will feature two chemists and two physicists.

Available in traditional print format, as an eBook, and

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online, this reference puts physical property data and mathematical formulas used in labs and classrooms every day within easy reach. New tables: Section 8: Analytical Chemistry Figures of Merit Common Symbols Used in Gas and Liquid Chromatographic Schematic Diagrams Varieties of Hyphenated Gas Chromatography with Mass Spectrometry Section 15: Practical Laboratory Data Standard Fittings for Compressed Gas Cylinders Plug and Outlet Configurations for Common Laboratory Devices Section 16: Health and Safety Information Abbreviations Used in the Assessment and Presentation of Laboratory Hazards Incompatible Chemicals Explosion (Shock) Hazards Water-Reactive Chemicals Testing Requirements for Peroxidizable Compounds Tests for the Presence of Peroxides Pyrophoric Compounds - Compounds That Are Reactive with Air Flammability Hazards of Common Solvents Selection of Laboratory Gloves Selection of Respirator Cartridges and Filters Selection of Protective Laboratory Garments Protective Clothing Levels Chemical Fume Hoods and Biological Safety Cabinets Gas Cylinder Safety and Stamped Markings Laser Hazards in the Laboratory General Characteristics of Ionizing Radiation for the Purpose of Practical Application of Radiation Protection Radiation Safety Units Significantly updated and expanded tables: Section 1: Basic Constants, Units, and Conversion Factors

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Update of Standard Atomic Weights (2013) Update of Atomic Masses and Abundances Section 8: Analytical Chemistry Expansion of Abbreviations and Symbols Used in Analytical Chemistry Section 9: Molecular Structure and Spectroscopy Update of Bond Dissociation Energies Section 12: Properties of Solids Major update and Expansion of Electron Stopping Powers Section 14: Geophysics, Astronomy, and Acoustics Major Update of Interstellar Molecules Update of Atmospheric Concentration of Carbon Dioxide, 1958-2013 Update of Global Temperature Trend, 1880-2013 Section 15: Practical Laboratory Data Major update of Reference Points on the ITS-90 Temperature Scale Update of Laboratory Solvents and Other Liquid Reagents Section 16: Health and Safety Information Update of Flammability of Chemical Substances Update of Threshold Limits for Airborne Contaminants to 2013 values Appendix B: Update of Sources of Physical and Chemical Data

The second, updated edition of this essential reference book provides a wealth of detail on a wide range of electronic and photonic materials, starting from fundamentals and building up to advanced topics and applications. Its extensive coverage, with clear illustrations and applications, carefully selected chapter sequencing and logical flow, makes it very different from other electronic materials handbooks. It has been written by professionals in the field and

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Instructors who teach the subject at a university or in corporate laboratories. The Springer Handbook of Electronic and Photonic Materials, second edition, includes practical applications used as examples, details of experimental techniques, useful tables that summarize equations, and, most importantly, properties of various materials, as well as an extensive glossary. Along with significant updates to the content and the references, the second edition includes a number of new chapters such as those covering novel materials and selected applications. This handbook is a valuable resource for graduate students, researchers and practicing professionals working in the area of electronic, optoelectronic and photonic materials.

Silicon carbide is known to have been investigated since 1907 when Captain H J Round demonstrated yellow and blue emission by applying bias between a metal needle and an SiC crystal. The potential of using SiC in semiconductor electronics was already recognized half a century ago. Despite its well-known properties, it has taken a few decades to overcome the exceptional technological difficulties of getting silicon carbide material to reach device quality and travel the road from basic research to commercialization. This second of two volumes reviews four important additional areas: the growth of SiC substrates; the deep defects in different SiC polytypes, which after many years of research still

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define the properties of bulk SiC and the performance and reliability of SiC devices; recent work on SiC JFETs; and the complex and controversial issues important for bipolar devices. Recognized leaders in the field, the contributors to this volume provide up-to-date reviews of further state-of-the-art areas in SiC technology and materials and device research. This book investigates the behavior of light (light pulse) within the micro- and nano-scale device (ring resonator), which can be integrated to form the device, circuits, and systems that can be used for atom/molecule trapping and transportation, optical transistor, fast calculation devices (optical gate), nanoscale communication and networks, and energy storage, etc. The large demand of small-scale device, especially, with light signal processing is needed. This book discusses device (nano device) design and simulation, which can be useful for practice in the near future.

The capture and use of solar energy has been growing for many years, but only in recent times have advances in design and manufacture allowed us to see the incorporation of solar energy as a significant player in the renewable energy arena. Solar cells are at the heart of any photovoltaic system and in this book the various types are described and their characteristics reviewed. Going beyond materials, design and function, 'Solar Cells'

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also covers their testing, monitoring and calibration thus providing a comprehensive account of current activity in this important field of research and industry. 'Solar Cells' has been abstracted from the recent 'Practical Handbook of Photovoltaics' by the same editors (ISBN 185617 3909. 2003: Elsevier) Internationally-respected contributors from industry and academia Abstracted from 'The Practical Handbook of Photovoltaics' by the same Editors A comprehensive source-book on all aspects of solar cells

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